

SEMICONDUCTOR TECHNICAL DATA

KIA6259P/S BIPOLAR LINEAR INTEGRATED CIRCUIT

LOW NOISE DUAL PRE-AMPLIFIER

The KIA6259P and KIA6259S are dual low noise pre-amplifier improved on operational amplifier(4558type) for consumer applications.

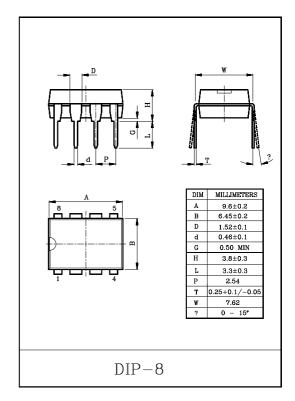
FEATURES

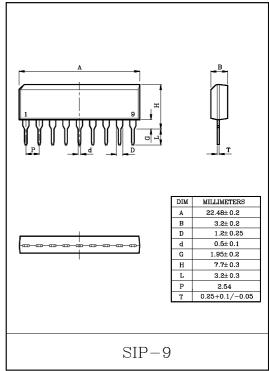
- · Wide operating supply voltage range
 - : V_{CC} , $V_{EE} \pm 1.5 V \sim \pm 18.0 V$
- · Low Noise, Low Distortion
 - : $V_{NI}=1\mu V_{rms}(Typ.)$
 - $(Rg=2.2k\Omega, NAB, f=1kHz, G_V=40dB)$
 - : THD=0.005%, $(V_{OUT}=2.0V_{rms})$
- The recommended closed loop voltage gain in more than 20dB.

MAXIMUM RATINGS (Ta=25℃)

CHARACTERIS	SYMBOL	RATING	UNIT		
Supply Voltage	V_{CC}	±22	V		
Power Dissipation (Note)	KIA6259P	D	500	mW	
	KIA6259S	P_{D}	750		
Operating Temperat	T_{opr}	-25~75	℃		
Storage Temperatur	T_{stg}	-55~150	$^{\circ}$		

Note : Derated about Ta=25°C in the proportion of 4mW/°C for KIA6259P, and of 6mW/°C for KIA6259S





KIA6259P/S

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{\text{CC}}\text{=}4.5V,~V_{\text{EE}}\text{=}-4.5V,~\text{f=}1kHz,~\text{Ta=}25\,^{\circ}\text{C}\,)$

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	ТҮР.	MAX.	UNIT
Quiescent Current	I_{CCQ}	1	$ m V_{IN}$ =0	-	2.7	4.0	mA
Equivalent Input Noise Voltage	$ m V_{NI}$	1	$Rg=2.2k\Omega$, NAB, $G_V=40dB$ $BW=20Hz\sim20kHz$	-	1.0	1.3	$\mu m V_{rms}$
Open Loop Voltage Gain	Gvo	1	$ m V_{OUT}$ =2.0 $ m V_{rms}$	75	85	_	dB
Total Harmonic distortion	THD	1	V_{OUT} =2.0 V_{rms}	_	0.005	0.01	%
Maximum Output Voltage	V_{OM}	1	THD=0.5%	2.0	2.7	-	$V_{\rm rms}$
Cross Talk	С.Т.	1	$Rg=2.2k\Omega$, $V_{OUT}=2.0V_{rms}$	65	76	_	dB
Input Bias Current	$ m I_{IB}$	1	-	-	0.65	-	μΑ

DC CHARACTERISTICS

 $(V_{CC}=4.5V, V_{EE}=-4.5V, Rg=2.2k\Omega, Terminal Voltage at No Signal)$

(Unit in mV)

TERMINAL NO.	1	2	3	4	5	6	7	8	9
KIA6259S	V_{CC}	15	75	75	$ m V_{EE}$	75	75	15	V_{CC}
KIA6259P	15	75	75	$V_{ ext{EE}}$	75	75	15	V_{CC}	-

EQUIVALENT CIRCUIT

